

PNP General Purpose Amplifier

This device is designed for general purpose amplifier and switching applications at collector currents to 10 µA as a switch and to 100 mA as an amplifier.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	4.0	V
Ic	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations. 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics

Symbol	Characteristic	Max		Units
		2N4126	*MMBT4126	
P _D	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

TA= 25°C unless otherwise noted

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

PNP General Purpose Amplifier (continued)

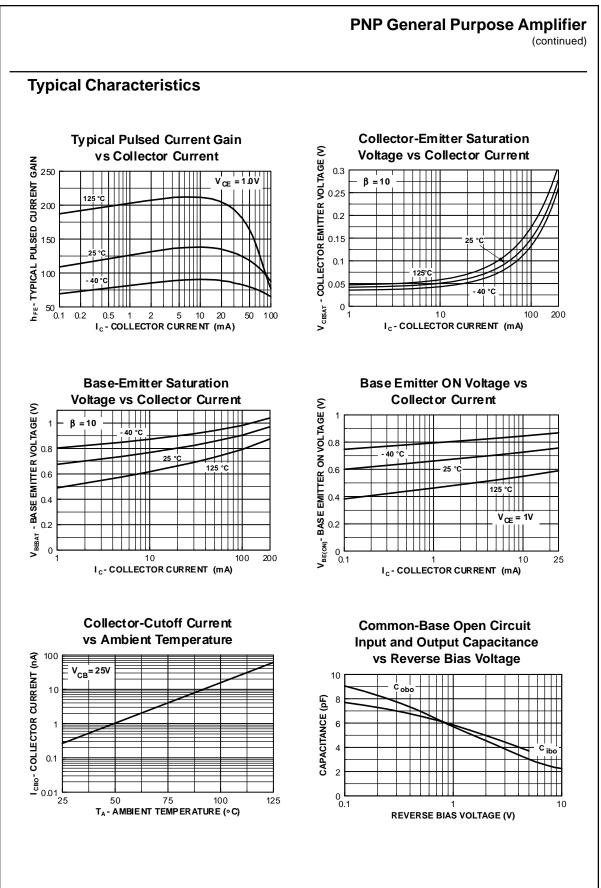
Electrical Characteristics TA=25°C unless otherwise noted								
Symbol	Parameter	Test Conditions	Min	Max	Units			
OFF CHAF	RACTERISTICS							
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{C} = 1.0 \text{ mA}, I_{B} = 0$	25		V			
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, \ I_{E} = 0$	25		V			
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	4.0		V			
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_{E} = 0$		50	nA			
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA			
ON CHAR	ACTERISTICS*							
h _{FE}	DC Current Gain	$I_{C} = 2.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$	120	360				
		$I_{\rm C} = 50$ mA, $V_{\rm CE} = 1.0$ V	60					
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA		0.4	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA		0.95	V			

SMALL SIGNAL CHARACTERISTICS

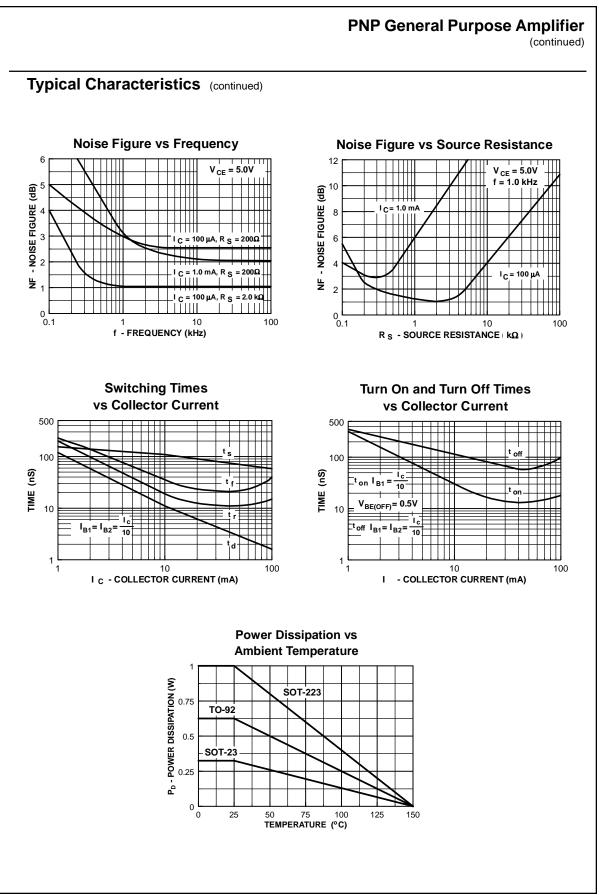
f _T	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	250		MHz
C _{ibo}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0,$ f = 1.0 MHz		10	pF
C _{cb}	Collector-Base Capcitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.5	pF
h _{fe}	Small-Signal Current Gain	$I_{C} = 2.0 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 1.0 kHz	120	480	
NF	Noise Figure	I_{c} = 100 μA, V _{CE} = 5.0 V, R _S =1.0 kΩ, f=10 Hz to 15.7 kHz		4.0	dB

*Pulse Test: Pulse Width ${\leq}\,300\,\mu\text{s},$ Duty Cycle ${\leq}\,2.0\%$

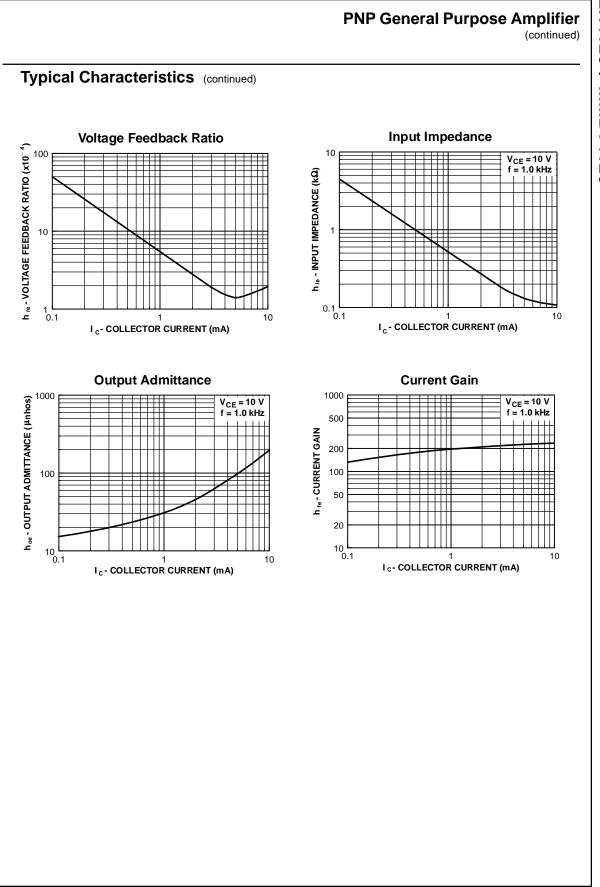
NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.



2N4126 / MMBT4126



2N4126 / MMBT4126



2N4126 / MMBT4126

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™ Bottomless™ CoolFET™ CROSSVOLT™ DOME™ E²CMOS[™] EnSigna™ FACT™ FACT Quiet Series[™] FAST[®]

FASTr™ GlobalOptoisolator™ GTO™ HiSeC™ **ISOPLANAR™** MICROWIRE™ OPTOLOGIC™ **OPTOPLANAR™** PACMAN™ POP™

PowerTrench[®] QFET™ QS™ QT Optoelectronics[™] Quiet Series[™] SILENT SWITCHER® SMART START™ SuperSOT[™]-3 SuperSOT[™]-6 SuperSOT[™]-8

SyncFET™ TinyLogic™ UHC™ VCX™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

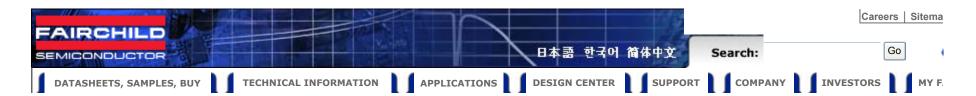
1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.



BUY

Datasheet

datasheet

X

<u></u> =- '

This page Print version

Download this

e-mail this datasheet

Home >> Find products >>

2N4126 PNP General Purpose Amplifier



•<u>General description</u> •<u>Product status/pricing/packaging</u> •<u>Order Samples</u> •<u>Models</u>

General description

This device is designed for general purpose amplifier and switch-ing applications at collector currents to 10 μA as a switch and to 100 mA as an amplifier.

back to top

Product status/pricing/packaging BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
2N4126BU	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	BULK	<u>Line 1:</u> 2N <u>Line 2:</u> 4126 <u>Line 3:</u> -&3
2N4126TA	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 4126 Line 3: -&3
2N4126TAR	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 4126 Line 3: -&3
2N4126TF	Full Production		\$0.025	<u>TO-92</u>	3	TAPE REEL	Line 1: 2N Line 2: 4126 Line 3: -&3

Related Links

- Request samples
- How to order products
- Product Change Notices (PCNs)
- <u>____</u>
- <u>Support</u>
- Sales support
- -----
- Quality and reliability
- Design center

		Full Production					
2N4126TFR	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	TAPE REEL	Line 1: 2N Line 2: 4126 Line 3: -&3

* Fairchild 1,000 piece Budgetary Pricing ** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a <u>Fairchild distributor</u> to obtain samples

Ø Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N4126 is available. <u>Click here for more information</u>.

back to top

Models

Package & leads	Condition	Temperature range	Software version	Revision date		
	PSPICE					
TO-92-3 Electrical 25°C N/A N/A						

back to top

Qualification Support

Click on a product for detailed qualification data

Product
2N4126BU
<u>2N4126TA</u>
2N4126TAR
2N4126TF
2N4126TFR

back to top

© 2007 Fairchild Semiconductor



Products | Design Center | Support | Company News | Investors | My Fairchild | Contact Us | Site Index | Privacy Policy | Site Terms & Conditions | Standard Terms & Conditions (